	<b>ESC</b>	C	DC	DCUMENT	CHANGE REQUEST		
DCR number	1419	Changes re	quired for: Gen	eral	Originator: Valeries Lepaludier		
Date: 2021/05	5/31	Date sent: 2021/04/09			Organisation: Atmel Microchip		
Status: IMPLEMENTED							
Title:	INTEGRATED CIF	NTEGRATED CIRCUITS, SILICON MONOLITHIC, CMOS, CELL-BASED ARRAY BASED ON TYPE					
Number:	9202/083		Issue:	3			
Other documents affected:							
Page:							
5 and 11 + minor corrections							
Paragraph:							
1.4.2 and 1.7							
Original wording:							
list of variant starting at 1							
Proposed wording:							
list of variant starting at 75 and adding pre-qualified IPs list							
Justification:							
remove all multi-decks packages option, only flat-substrate package available.							
Attachments:							
escc9202083iss4_draft_c_for_review.docx, escc9202083iss4_draft.docx							
Modifications:							
The original Draft Spec attachment is modified and accepted as follows:							
<ul> <li>Title is re-worded (for clarification).</li> <li>Para. 1.5 is modified with editorial changes for improved readability and homogeneity with other specs.</li> <li>The new Para. 1.7 is re-worded for clarity and conciseness.</li> <li>Para. 2.4: The IIL and IIH Drift and Absolute Values for LVDS Buffers are re-instated (deleted by mistake in the original Draft).</li> </ul>							
Approval signature:							
Attende							

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2021-05-31